

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	801579	gate\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:11
L2	251743	implant\$3 or doping	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:11
L3	442424	impurit\$3 or dopant\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:12
L4	932684	semiconduct\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:12
L5	1350617	channel\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:12
L6	216819	source\$1 same drain\$1	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:14
L7	57381	soi or (silicon adj2 insulat\$3)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:14
L8	43063	(thin adj film) adj (transistor\$1 or device\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:14
L9	127626	polysilicon or polysi or (polycrystalline adj (silicon or si)) or poly-si	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:15

L10	79995	1 and 4 and 5 and 6	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:15
L11	68169	2 same 3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:16
L12	1632	7 and 8 and 9	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:16
L13	867	10 and 11 and 12	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:17
L14	20665	carrier\$1 near2 inject\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:17
L15	126	13 and 14	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:17
L16	741	13 not 15	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/05/04 11:17